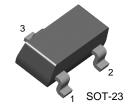


FJV992

Audio Frequency Low Noise Amplifier

• Complement to FJV1845



1. Base 2. Emitter 3. Collector

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	-120	V
V _{CEO}	Collector-Emitter Voltage	-120	V
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current	-50	mA
P _C	Collector Power Dissipation	300	mW
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

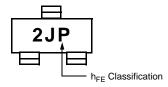
Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C = -100μA, I _E =0	-120		V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I_C = -1mA, I_B =0	-120		V
BV _{EBO}	Emitter-Emitter Breakdown Voltage	$I_E = -10\mu A, I_C = 0$	-5		V
I _{EBO}	Emitter-Base Cutoff Current	V_{EB} = -6V, I_{C} =0		-30	nA
h _{FE1}	DC Current Gain	$V_{CE} = -6V, I_{C} = -0.1 \text{mA}$	150		
h_{FE2}		V_{CE} = -6V, I_{C} = -1mA	200	800	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = -10mA, I _B = -1mA		-300	mV
V _{BE} (on)	Base-Emitter On Voltage	V_{CE} = -6V, I_{C} = -1mA	-0.55	-0.65	V
f _T	Current Gain Bandwidth Product	V _{CE} = -6V, I _C = -1mA	50		MHz
C _{ob}	Output Capacitance	V _{CB} = -30V, I _E =0, f=1MHz		3	pF
NV	Noise Voltage			40	mV

h_{FE2} Classification

Classification	Р	F	Е
h _{FE2}	200 ~ 400	300 ~ 600	400 ~ 800

Marking



Typical Characteristics

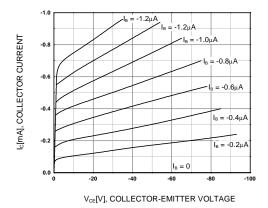


Figure 1. Static Characteristic

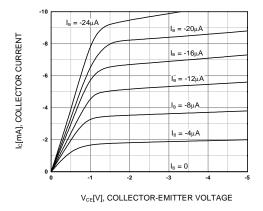


Figure 2. Static Characteristic

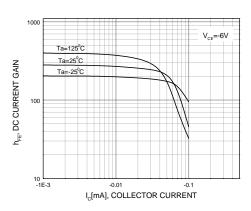


Figure 3. DC current Gain

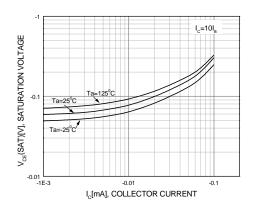


Figure 4. Collector-Emitter Saturation Voltage

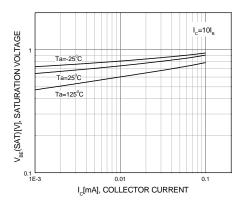


Figure 5. Base-Emitter Saturation Voltage

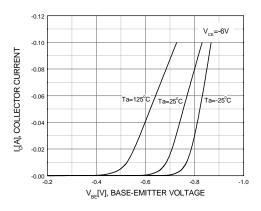


Figure 6. Base-Emitter Voltage

Typical Characteristics (Continued)

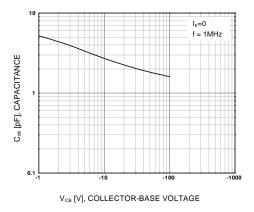


Figure 7. Collector Output Capacitance

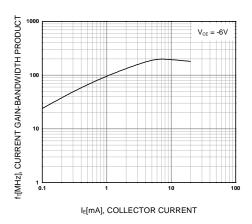


Figure 8. Current Gain Bandwidth Product

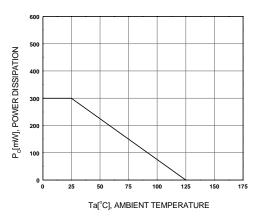
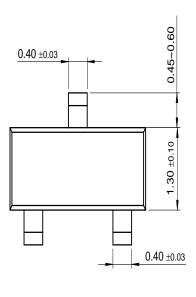
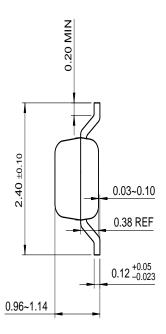


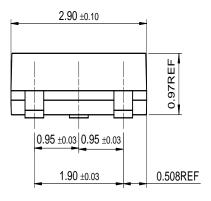
Figure 9. Power Derating

Package Dimensions

SOT-23







Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench [®]	SuperSOT™-6
$CROSSVOLT^{TM}$	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I^2C^{TM}	OCX^{TM}	RapidConfigure™	UHC™
Across the board.	Around the world.™	OCXPro™	RapidConnect™	UltraFET [®]
The Power Franchise™		OPTOLOGIC [®]	SILENT SWITCHER®	VCX TM
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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